TOSHIBA 2SD799

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

2 S D 7 9 9

IGNITER APPLICATIONS

HIGH VOLTAGE SWITCHING APPLICATIONS

High DC Current Gain: $h_{FE} = 600$ (Min.) $(V_{CE} = 2 V, I_{C} = 2 A)$

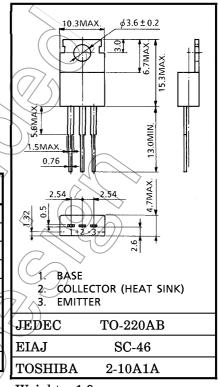
Monolithic Construction with Built-In Base-Emitter Shunt Resistor.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	AMI
Collector-Base Voltage	v_{CBO}	600 (//	/
Collector-Emitter Voltage	v_{CEO}	400	V
Emitter-Base Voltage	$V_{ m EBO}$	(5)	V
Collector Current	$I_{\mathbf{C}}$	6	A
Base Current	IB	1	A
Collector Power Dissipation (Tc = 25°C)	PC	30	w
Junction Temperature	T_j	150 //	°C/
Storage Temperature Range	Tstg	-55~150	° ℃

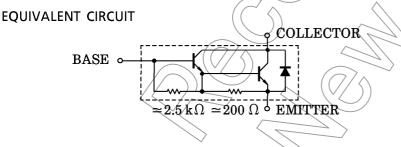
INDUSTRIAL APPLICATIONS

Unit in mm



Weight: 1.9 g

Mounting Kit No. AC75



TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail—due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

The information contained herein is presented only as a guide for the applications of our products. No responsibility

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
 The information contained herein is subject to change without notice.

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARAC	TERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-	off Current	I_{CBO}	$V_{CB} = 600 \text{ V}, I_{E} = 0$	74	_	0.5	mA
Emitter Cut-of	f Current	I_{EBO}	$V_{EB} = 5 V$, $I_C = 0$		-	3	mA
Collector-Emit Voltage	ter Breakdown	V (BR) CEO	$I_{C} = 10 \text{ mA}, I_{B} = 0$	400	_		V
DC Current Gain		h _{FE (1)}	$V_{CE} = 2 V, I_C = 2 A$	600			
		h _{FE} (2)	$V_{CE} = 2 V$, $I_{C} = 4 A$	100	_		
Collector-Emit Voltage	ter Saturation	V _{CE} (sat)	$I_C = 4 A, I_B = 0.04 A$		1 (2.0	V
Base-Emitter S Voltage	Saturation	V _{BE} (sat)	$I_C = 4 A, I_B = 0.04 A$	_<		$>_{2.5}$	V
Emitter-Collec Voltage	tor Forward	$v_{\rm ECF}$	$I_E = 4 A$, $I_B = 0$			3.0	V
Collector Outp	ut Capacitance	C_{ob}	$V_{CB} = 50 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		35	-	pF
Switching Time	Turn-on Time	t _{on}	OUTPUT 20 \(\nu\)S PUT \(\mathbb{IB1}\) C		1		
	Storage Time	${ m t_{stg}}$	IB1 IB2 IB2 IB2 IB2	8	_	μ s	
	Fall Time	t _f	$I_{B1} = -I_{B2} = 0.04 \text{ A}, V_{CC}^{**}$ DUTY CYCLE \(\leq 1\%) = 100 V		5	_	

